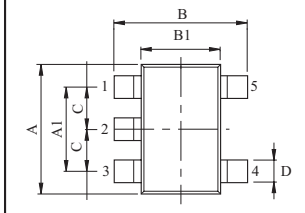
KRC657U~KRC659U

EPITAXIAL PLANAR NPN TRANSISTOR

SWITCHING APPLICATION.
INTERFACE CIRCUIT AND DRIVER CIRCUIT APPLICATION.

FEATURES

- With Built-in Bias Resistors.
- Simplify Circuit Design.
- Reduce a Quantity of Parts and Manufacturing Process.
- High Packing Density.

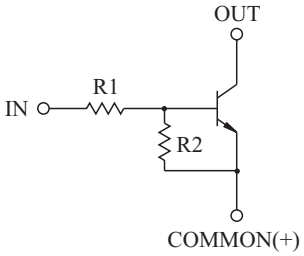


DIM	MILLIMETERS
A	2.00±0.20
A1	1.3±0.1
B	2.1±0.1
B1	1.25±0.1
C	0.65
D	0.2+0.10/-0.05
G	0-0.1
H	0.9±0.1
T	0.15+0.1/-0.05

1. Q_1 IN (BASE)
2. Q_1, Q_2 COMMON (EMITTER)
3. Q_2 IN (BASE)
4. Q_2 OUT (COLLECTOR)
5. Q_1 OUT (COLLECTOR)

USV

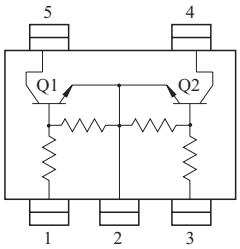
EQUIVALENT CIRCUIT



BIAS RESISTOR VALUES

TYPE NO.	R1(kΩ)	R2(kΩ)
KRC657U	10	47
KRC658U	22	47
KRC659U	47	22

EQUIVALENT CIRCUIT (TOP VIEW)



MAXIMUM RATING (Ta=25℃)

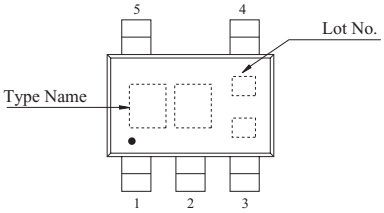
CHARACTERISTIC		SYMBOL	RATING	UNIT
Output Voltage	KRC657U～659U	V_O	50	V
Input Voltage	KRC657U	V_I	30, -6	V
	KRC658U		40, -7	
	KRC659U		40,-15	
Output Current	KRC657U～659U	I_O	100	mA
Power Dissipation		P_D*	200	mW
Junction Temperature		T_j	-55~150	℃
Storage Temperature Range		T_{stg}	-55~150	℃

* Total Rating.

MARK SPEC

TYPE	KRC657U	KRC658U	KRC659U
MARK	NH	NI	NJ

Marking

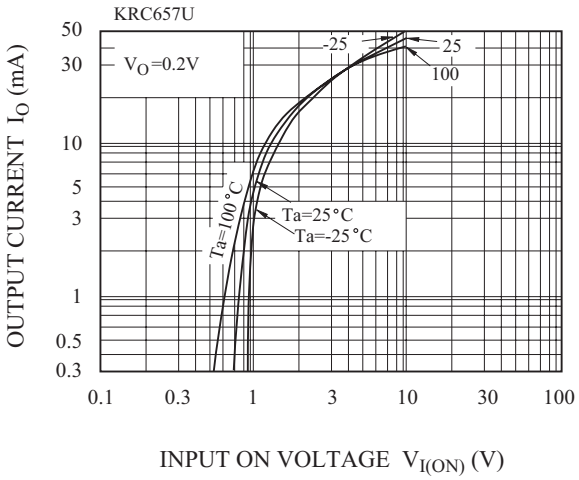


ELECTRICAL CHARACTERISTICS (Ta=25℃)

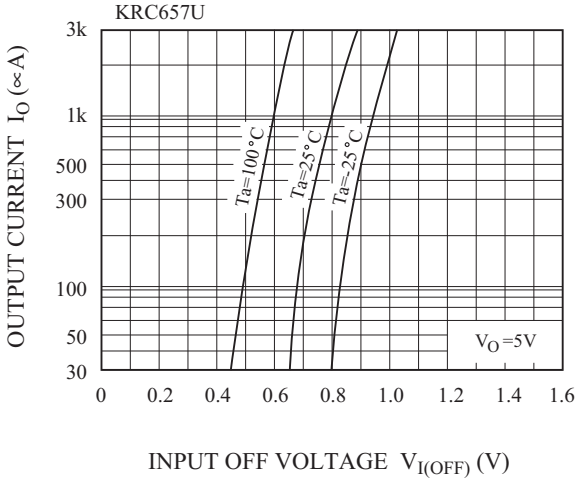
CHARACTERISTIC			SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Cut-off Current		KRC657U ~659U	$I_{O(OFF)}$	V_O=50V, V_I=0	-	-	500	nA
DC Current Gain		KRC657U	G_I	V_O=5V, I_O=10mA	80	150	-	
		KRC658U			80	150	-	
		KRC659U			70	140	-	
Output Voltage		KRC657U ~659U	$V_{O(ON)}$	I_O=10mA, I_I=0.5mA	-	0.1	0.3	V
Input Voltage (ON)		KRC657U	$V_{I(ON)}$	V_O=0.2V, I_O=5mA	-	1.2	1.8	V
		KRC658U			-	1.8	2.6	
		KRC659U			-	3.0	5.8	
Input Votlage (OFF)		KRC657U	$V_{I(OFF)}$	V_O=5V, I_O=0.1mA	0.5	0.75	-	V
		KRC658U			0.6	0.88	-	
		KRC659U			1.5	1.82	-	
Transition Frequency		KRC657U ~659U	f_T *	V_O=10V, I_O=5mA	-	200	-	MHz
Input Current		KRC657U	I_I	V_I=5V	-	-	0.88	mA
		KRC658U			-	-	0.36	
		KRC659U			-	-	0.16	
Switching Time	Rise Time	KRC657U	t_r	V_O=5V, V_{IN}=5V R_L=1kΩ	-	0.05	-	μs
		KRC658U			-	0.12	-	
		KRC659U			-	0.26	-	
	Storage Time	KRC657U	t_{stg}		-	2.0	-	
		KRC658U			-	2.4	-	
		KRC659U			-	1.5	-	
	Fall Time	KRC657U	t_f		-	0.36	-	
		KRC658U			-	0.4	-	
		KRC659U			-	0.41	-	
Input Resistor		KRC657U	R1	-	7	10	13	kΩ
		KRC658U			15.4	22	28.6	
		KRC659U			32.9	47	61.1	
Resistor Ratio		KRC657U	R2/R1	-	3.7	4.7	5.7	
		KRC658U			1.7	2.1	2.6	
		KRC659U			0.37	0.47	0.57	

Note : * Characteristic of Transistor Only.

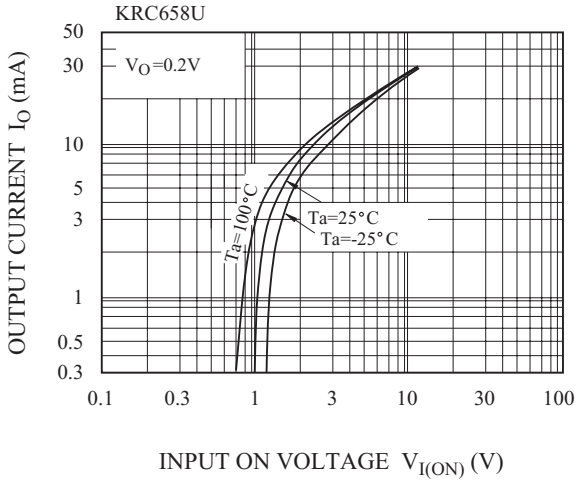
I_O - $V_{I(ON)}$



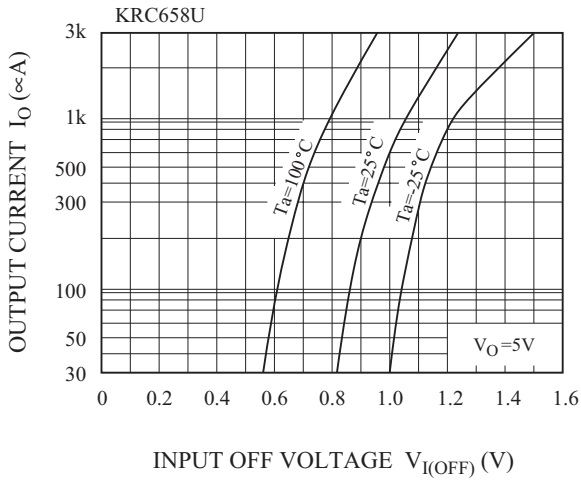
I_O - $V_{I(OFF)}$



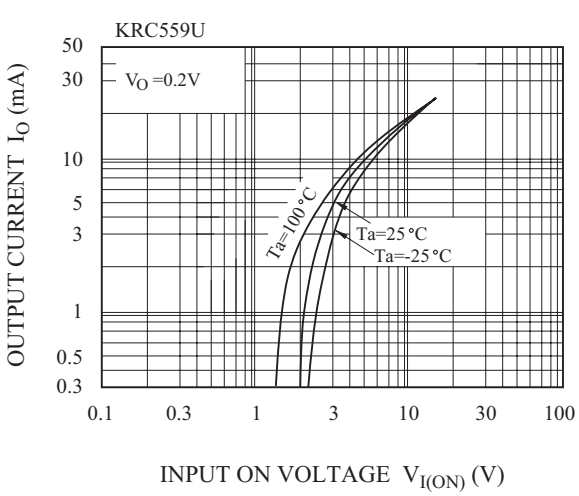
I_O - $V_{I(ON)}$



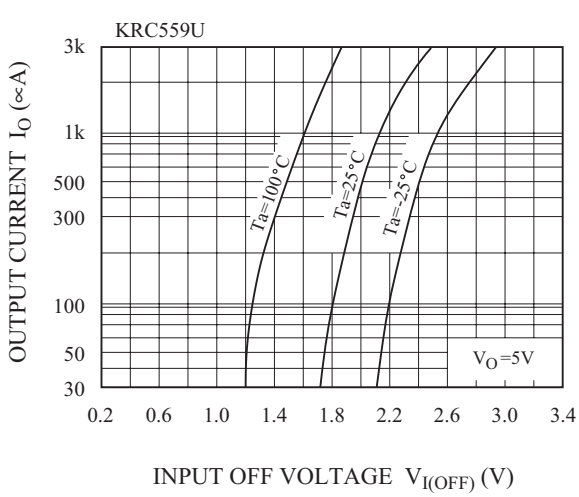
I_O - $V_{I(OFF)}$



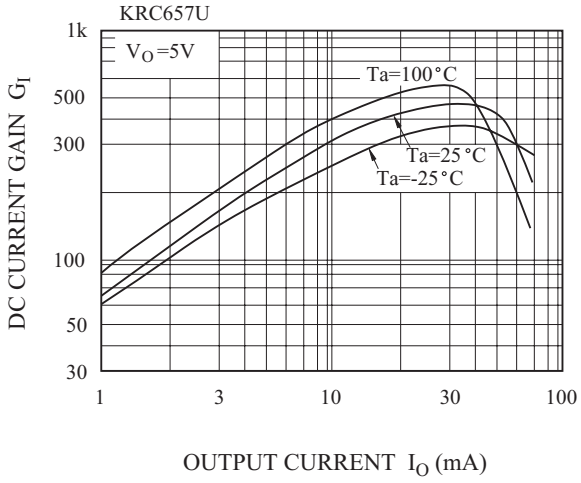
I_O - $V_{I(ON)}$



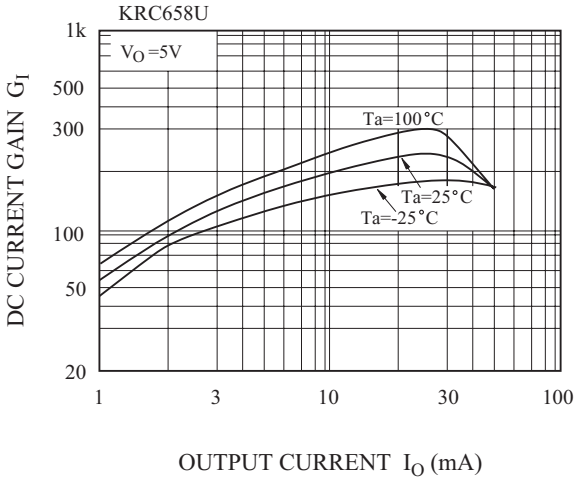
I_O - $V_{I(OFF)}$



G_I - I_O



G_I - I_O



G_I - I_O